

QT-Brightek PLCC-4 Series

PLCC-4 Single Color LED

Part No.: QBLP677A-XXD Series

**A: Common Anode
XX = Color Code
D = 50mA Sorting**



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Introduction

Feature:

- Water clear lens
- AlInGaP technology for R/S/Y/O
- InGaN technology IB/IG
- Common anode
- 120 degree viewing angle
- Height profile: 1.85mm

Application:

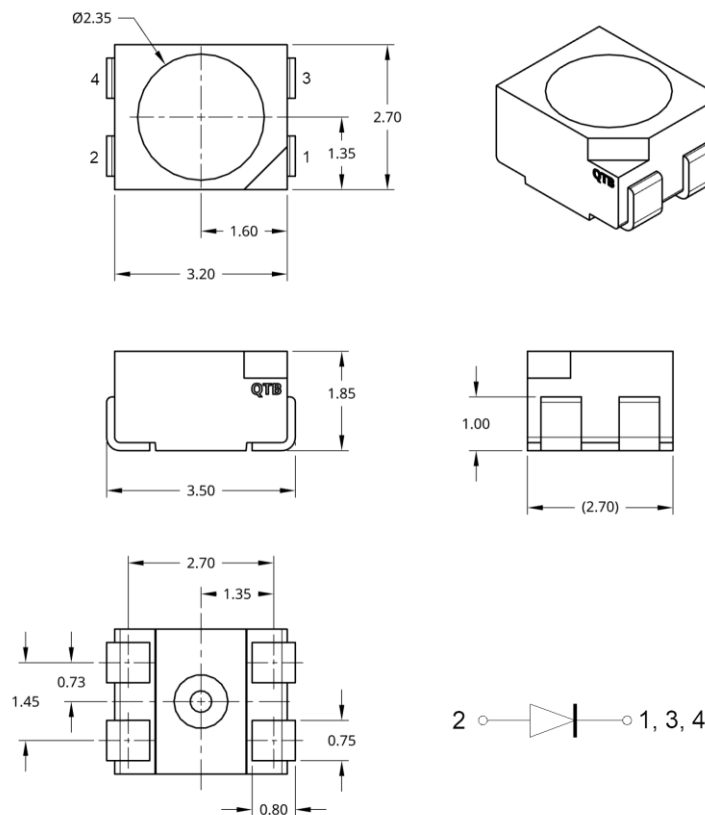
- Status indication
- Industrial equipment backlighting
- Architecture lighting

Certification & Compliance:

- ISO9001
- RoHS Compliant



Dimension:



Units: mm / tolerance = +/-0.2mm

Electrical / Optical Characteristic (Ta=25 °C)

Product	Color	I _F (mA)	V _F (V)		λ _D (nm)			λ _P (nm)	I _V (mcd)		
			Typ.	Max.	Min.	Typ.	Max.	Typ.	Min.	Typ.	Max.
QBLP677A-RD	Red	50	2.1	2.9	615	620	630	630	1250	2050	4000
QBLP677A-SD	Deep Red		2.1	2.9	630	640	650	654	100	170	320
QBLP677A-YD	Yellow		2.1	2.9	585	590	595	594	1000	1600	2500
QBLP677A-OD	Orange		2.7	2.9	600	605	610	612	1250	2400	4000
QBLP677A-IGD	Green		3.3	3.7	515	520	525	515	2500	5000	6800
QBLP677A-IBD	Blue		3.2	3.8	465	470	475	465	320	585	1000

Absolute Maximum Rating

Material	P _d (mW)	I _F (mA)	I _{FP} (mA)*	V _R (V)	T _{OP} (°C)	T _{ST} (°C)	T _{SOL} (°C)**
AlInGaP	145	50	250	5	-40 to +85	-40 to +100	260
InGaN	200	50	250	5	-40 to +85	-40 to +100	260

*Duty 1/8 @ 1kHz

**IR Reflow for no more than 10 sec @ 260 °C

Forward Voltage V_F for AlInGaP (R, S, Y, O) @ I_F=50mA

Bin	Min.	Max.	Unit
□	1.9	2.9	V

Forward Voltage V_F for InGaN (IG, IB) @ I_F=50mA

Bin	Min.	Max.	Unit
f	2.8	3.1	V
g	3.1	3.4	
h	3.4	3.7	
i	3.7	4.0	

Luminous Intensity @ $I_F=50\text{mA}$

Bin	Min.	Max.	Unit
J	100	125	mcd
K	125	160	
L	160	200	
M	200	250	
N	250	320	
O	320	400	
P	400	500	
Q	500	630	
R	630	800	
S	800	1000	
T	1000	1250	
U	1250	1600	
V	1600	2000	
W	2000	2500	
X	2500	3200	
Y	3200	4000	
Z	4000	5200	
a	5200	6800	

Dominant Wavelength λ_D for Red @ $I_F=50\text{mA}$

Bin	Min.	Max.	Unit
s	615	620	nm
t	620	625	
u	625	630	

Dominant Wavelength λ_D for Deep Red @ $I_F=50\text{mA}$

Bin	Min.	Max.	Unit
v	630	635	nm
w	635	650	

Dominant Wavelength λ_D for Yellow @ $I_F=50\text{mA}$

Bin	Min.	Max.	Unit
m	585	590	nm
n	590	595	

Dominant Wavelength λ_D for Orange @ $I_F=50\text{mA}$

Bin	Min.	Max.	Unit
p	600	605	nm
q	605	610	



Dominant Wavelength λ_D for True Green @ $I_F=50\text{mA}$

Bin	Min.	Max.	Unit
S	515	517.5	nm
T	517.5	520	
U	520	522.5	
V	522.5	525	

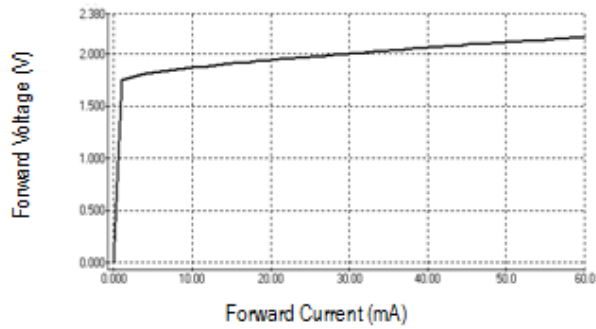
Dominant Wavelength λ_D for Blue @ $I_F=50\text{mA}$

Bin	Min.	Max.	Unit
G	465	467.5	nm
H	467.5	470	
I	470	472.5	
J	472.5	475	

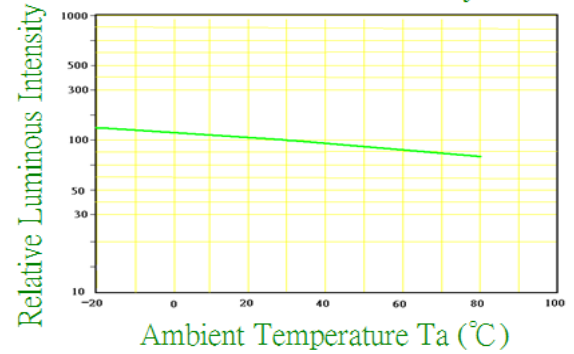
Characteristic Curves

AlInGaP

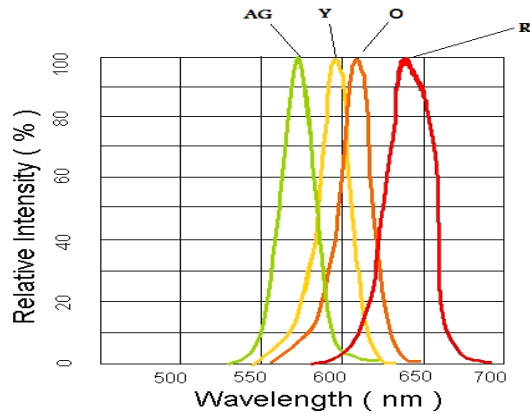
Forward Current vs. Forward Voltage



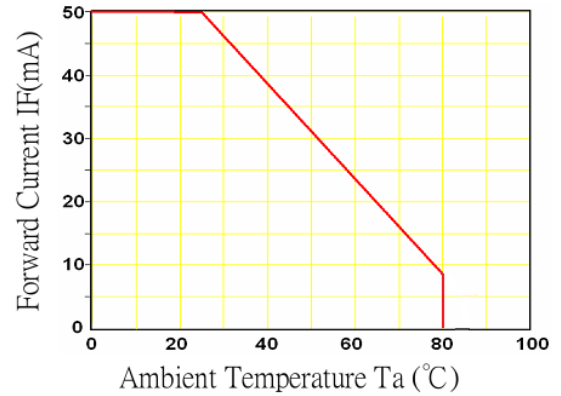
Relative Luminous Intensity-Ta



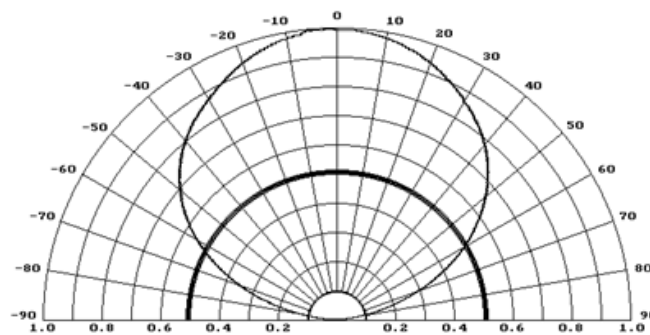
Relative Intensity vs. Wavelength



IF-Ta

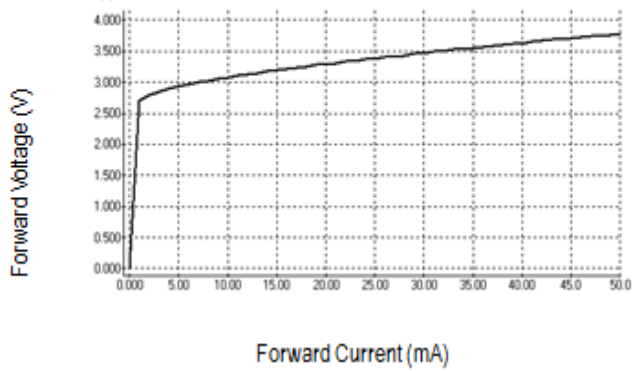


Directive Characteristics

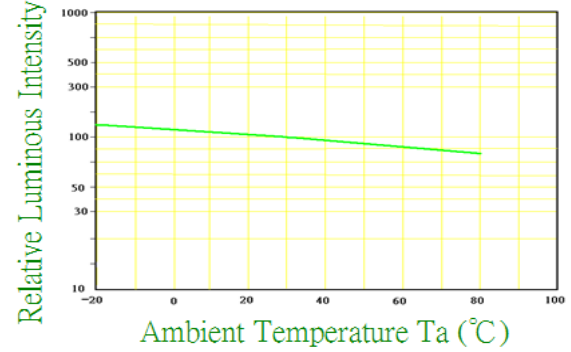


InGaN

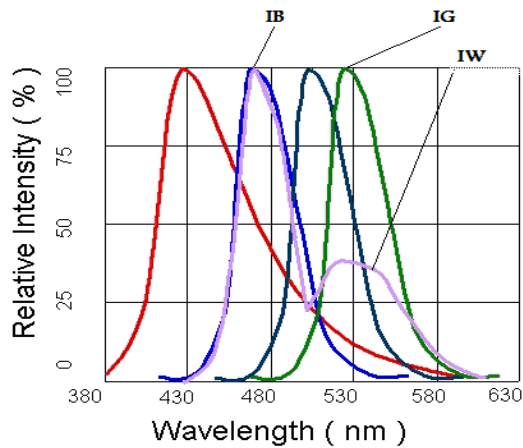
Forward Current vs. Forward Voltage



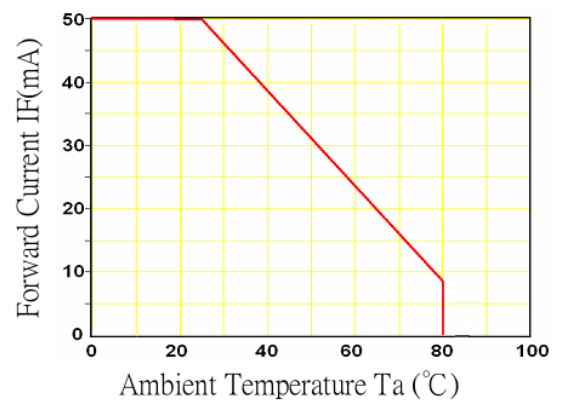
Relative Luminous Intensity-Ta



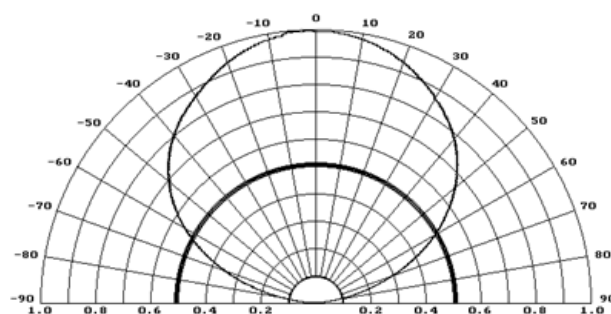
Relative Intensity vs. Wavelength



IF-Ta

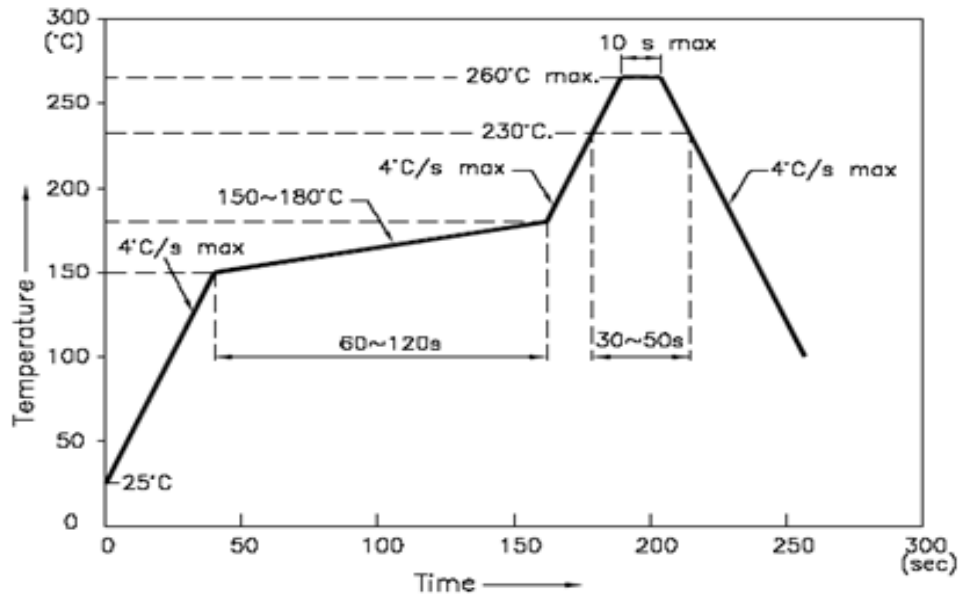


Directive Characteristics

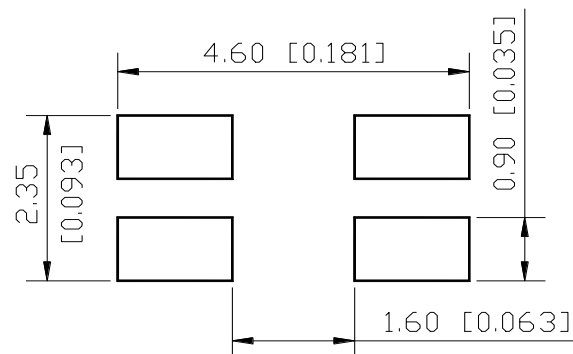


Solder Profile & Footprint

-The recommended reflow soldering profile is as follows (temperatures indicated are as measured on the surface of the LED resin):



Recommended Pad Layout

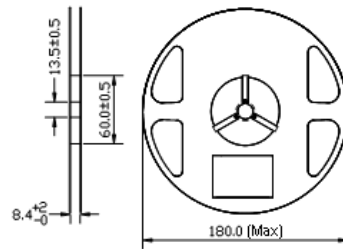


Units: mm

Tolerance: $\pm 0.1\text{mm}$

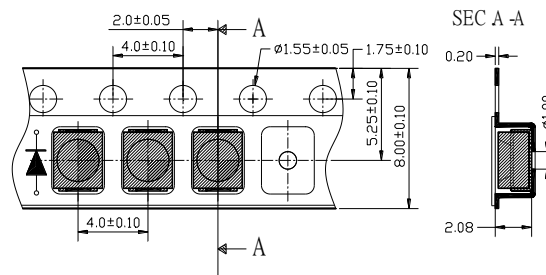
Packing

Reel Dimension:



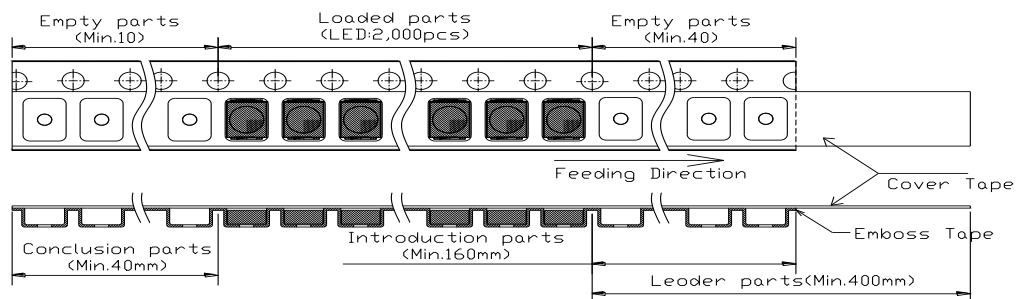
Unit: mm

Tape Dimension:



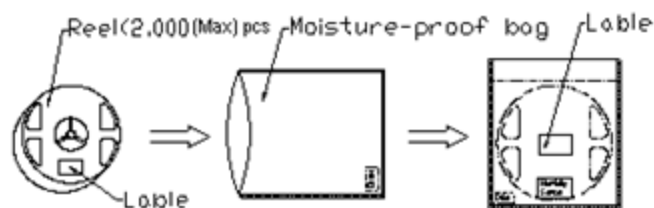
Unit: mm

Arrangement of Tape:



Unit: mm

Packaging Specifications:





Labeling



Part No: _____
Customer P/N: _____
Item: _____
Q'ty: _____
Vf: _____
Iv: _____
WI: _____
Date: _____

Made in China

Ordering Information

Orderable Part #	Spec Range	Quantity per reel
QBLP677A-RD	Iv=2050mcd typ. @ I _F =50mA / λ _d =615-630nm	2,000 units
QBLP677A-SD	Iv=170mcd typ. @ I _F =50mA / λ _d =630-650nm	2,000 units
QBLP677A-YD	Iv=1600mcd typ. @ I _F =50mA / λ _d =585-595nm	2,000 units
QBLP677A-OD	Iv=2400mcd typ. @ I _F =50mA / λ _d =600-610nm	2,000 units
QBLP677A-IGD	Iv=1550mcd typ. @ I _F =50mA / λ _d =515-525nm	2,000 units
QBLP677A-IBD	Iv=585mcd typ. @ I _F =50mA / λ _d =465-475nm	2,000 units



Revision History

Description:	Revision #	Revision Date
New Release of QBLP677A-XXD Series	V1.0	10/23/2015
Update Top and T _{ST}	V1.1	03/18/2016

Disclaimer

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QT-BRIGHTEK's products are not authorized for use as critical components in life support devices or systems without the express written approval of QT-BRIGHTEK. As used herein:

1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury of the user.
2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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